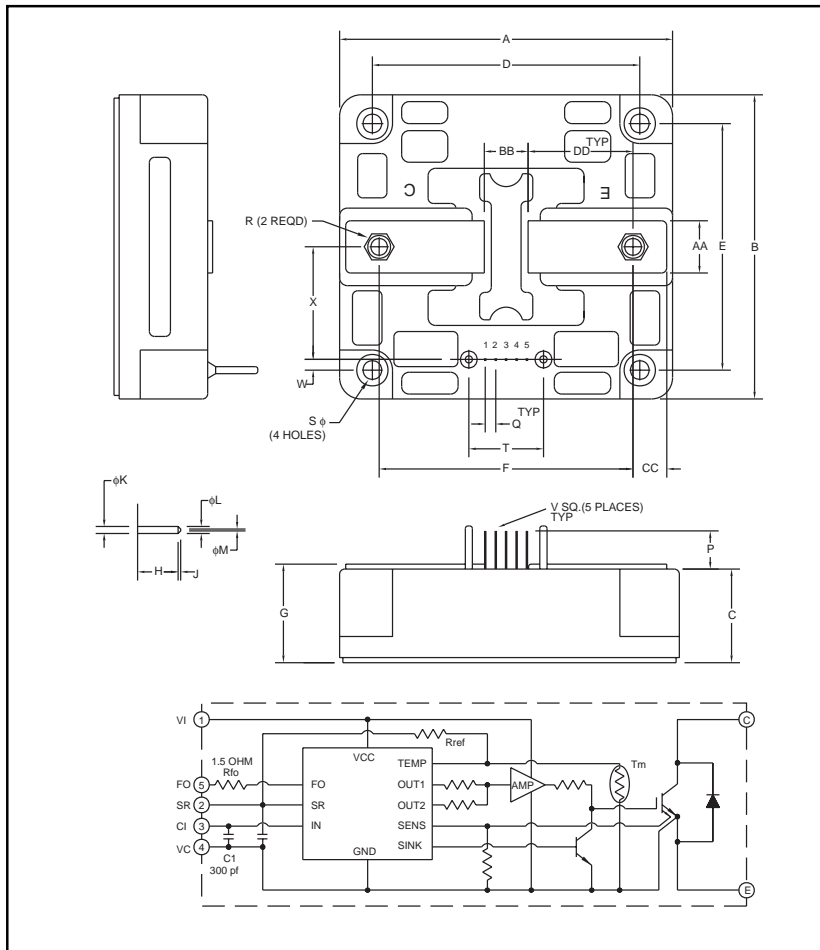


PM800HSA120

FLAT-BASE TYPE
INSULATED PACKAGE



Outline Drawing and Circuit Diagram



Description:

Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:

- Complete Output Power Circuit
- Gate Drive Circuit
- Protection Logic
 - Short Circuit
 - Over Current
 - Over Temperature
 - Under Voltage

Applications:

- Inverters
- UPS
- Motion/Servo Control
- Power Supplies

Ordering Information:

Example: Select the complete part number from the table below -i.e. PM800HSA120 is a 1200V, 800 Ampere Intelligent Power Module.

Type	Current Rating Amperes	V _{CES} Volts (x 10)
PM	800	120

Dimensions	Inches	Millimeters
A	3.94	100.0
B	5.20	132.0
C	1.33	33.7
D	3.23±0.010	82.0±0.25
E	4.33±0.010	110.0±0.25
F	2.84	72.0
G	1.42+0.04/-0.02	36.0+1/-0.5
H	0.53	13.5
J	0.06	1.5
K	0.17	4.4
L	0.15	3.8
M	0.06	1.5
N	0.35	9.0
P	0.53	13.5

Dimensions	Inches	Millimeters
Q	0.10	2.54
R	M8 Metric	M8
S	φ 6.5	φ 6.5
T	0.24	26.0
U	0.26	6.5
V	0.25	0.64
W	0.20	5.0
X	1.97	50.0
AA	0.71	18.0
BB	0.55	14.0
CC	0.39	10.0
DD	1.14.	29.0

PM800HSA120

**FLAT-BASE TYPE
INSULATED PACKAGE**

Absolute Maximum Ratings, $T_j = 25^\circ\text{C}$ unless otherwise specified

	Symbol	Ratings	Units
Power Device Junction Temperature	T_j	-20 to 150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-40 to 125	$^\circ\text{C}$
Case Operating Temperature	T_C	-20 to 100	$^\circ\text{C}$
Mounting Torque, M6 Mounting Screws	—	3.92 ~ 5.88	N · m
Mounting Torque, M8 Main Terminal Screws	—	8.83 ~ 10.8	N · m
Module Weight (Typical)	—	1170	Grams
Supply Voltage Protected by OC and SC ($V_D = 13.5 - 16.5\text{V}$, Inverter Part)	$V_{\text{CC(prot.)}}$	800	Volts
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{iso}	2500	Vrms

Control Sector

Supply Voltage Applied between (V_1 - V_C)	V_D	20	Volts
Input Voltage Applied between (C_1 - V_C)	V_{CIN}	10	Volts
Fault Output Supply Voltage (Applied between F_O - V_C)	V_{FO}	20	Volts
Fault Output Current (Fault Current of F_O Terminal)	I_{FO}	20	mA

IGBT Inverter Sector

Collector-Emitter Voltage ($V_D = 15\text{V}$, $V_{\text{CIN}} = 5\text{V}$)	V_{CES}	1200	Volts
Collector Current, ($T_C = 25^\circ\text{C}$)	I_C	800	Amperes
Peak Collector Current, ($T_C = 25^\circ\text{C}$)	I_{CP}	1600	Amperes
Collector Dissipation	P_C	4630	Watts

PM800HSA120FLAT-BASE TYPE
INSULATED PACKAGE**Electrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Over Current Trip Level Inverter Part	OC	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $V_D = 15\text{V}$	1060	1300	—	Amperes
Short Circuit Trip Level Inverter Part	SC	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $V_D = 15\text{V}$	1350	1700	—	Amperes
Over Current Delay Time	$t_{\text{off}}(\text{OC})$	$V_D = 15\text{V}$	—	5	—	μs
Over Temperature Protection	OT	Trip Level	100	110	120	$^\circ\text{C}$
	OT_r	Reset Level	85	95	105	$^\circ\text{C}$
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
	UV_r	Reset Level	—	12.5	—	Volts
Supply Voltage	V_D	Applied between V_1 - V_C	13.5	15	16.5	Volts
Circuit Current	I_D	$V_D = 15\text{V}$, $V_{\text{CIN}} = 5\text{V}$, V_1 - V_C	—	23	40	mA
Input ON Threshold Voltage	$V_{\text{CIN(on)}}$	Applied between C_1 - V_C	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{\text{CIN(off)}}$	Applied between C_1 - V_C	1.7	2.0	2.3	Volts
PWM Input Frequency	f_{PWM}	3- ϕ Sinusoidal	—	15	20	kHz
Fault Output Current	$I_{\text{FO(H)}}$	$V_D = 15\text{V}$, $V_{\text{FO}} = 15\text{V}$	—	—	0.01	mA
	$I_{\text{FO(L)}}$	$V_D = 15\text{V}$, $V_{\text{FO}} = 15\text{V}$	—	10	15	mA
Minimum Fault Output Pulse Width	t_{FO}	$V_D = 15\text{V}$	1.0	1.8	—	ms
SR Terminal Output Voltage	V_{SR}	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$, $R_{\text{in}} = 6.8\text{k}\Omega$	4.5	5.1	5.6	Volts

PM800HSA120

FLAT-BASE TYPE
INSULATED PACKAGEElectrical and Mechanical Characteristics, $T_j = 25^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector Cutoff Current	I_{CES}	$V_{CE} = V_{CES}, T_j = 25^\circ\text{C}$	—	—	1.0	mA
		$V_{CE} = V_{CES}, T_j = 125^\circ\text{C}$	—	—	10	mA
Emitter-Collector Voltage	V_{EC}	$-I_C = 800\text{A}, V_D = 15\text{V}, V_{CIN} = 5\text{V}$	—	2.6	3.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 800\text{A}, T_j = 25^\circ\text{C}$	—	2.5	3.5	Volts
		$V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 800\text{A}, T_j = 125^\circ\text{C}$	—	2.3	3.3	Volts
Inductive Load Switching Times	t_{on}		0.5	1.4	2.5	μs
	t_{rr}	$V_D = 15\text{V}, V_{CIN} = 0 \leftrightarrow 5\text{V}$	—	0.2	0.4	μs
	$t_{C(on)}$	$V_{CC} = 600\text{V}, I_C = 800\text{A}$	—	0.4	1.0	μs
	t_{off}	$T_j = 125^\circ\text{C}$	—	3.0	4.0	μs
	$t_{C(off)}$		—	0.6	1.1	μs

Thermal Characteristics

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Each IGBT	—	—	0.027	$^\circ\text{C}/\text{Watt}$
	$R_{th(j-c)F}$	Each FWDi	—	—	0.045	$^\circ\text{C}/\text{Watt}$
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	—	—	0.022	$^\circ\text{C}/\text{Watt}$

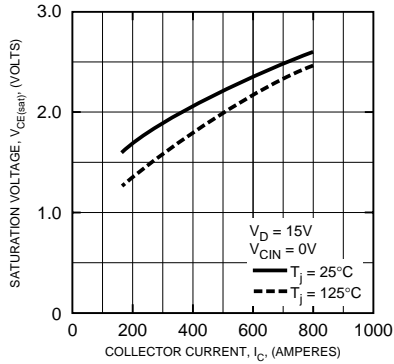
Recommended Conditions for Use

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across C1-E2 Terminals	0 ~ 800	Volts
	V_D	Applied between V_1 - V_C	15 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between C_1 - V_C	0 ~ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$	Applied between C_1 - V_C	$4.0 \sim V_{SR}$	Volts
PWM Input Frequency	f_{PWM}	Using Application Circuit	5 ~ 20	kHz
Minimum Dead Time	t_{dead}	Input Signal	≥ 4.0	μs

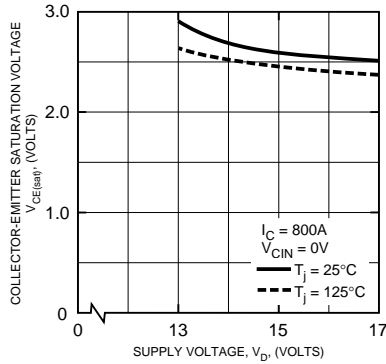
PM800HSA120

FLAT-BASE TYPE
INSULATED PACKAGE

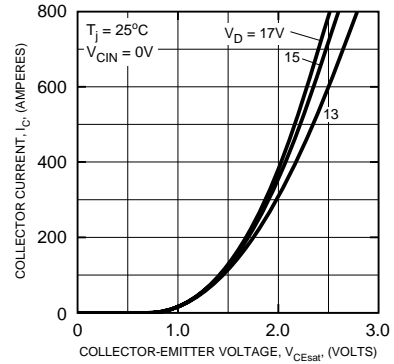
SATURATON VOLTAGE CHARACTERISTICS (TYPICAL)



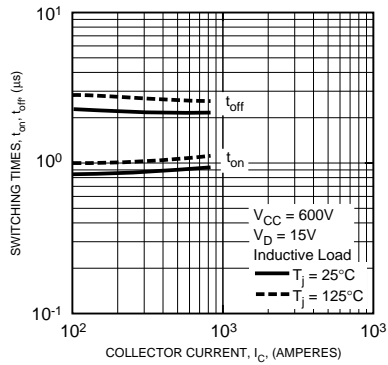
COLLECTOR-EMITTER SATURATON VOLTAGE CHARACTERISTICS (TYPICAL)



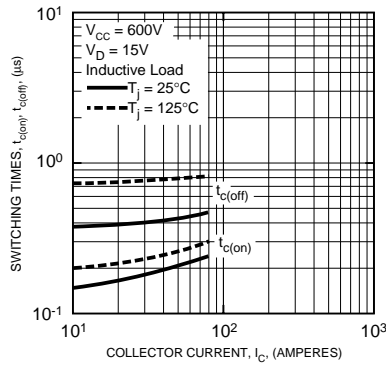
OUTPUT CHARACTERISTICS (TYPICAL)



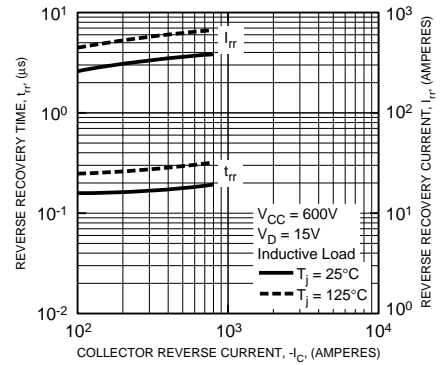
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



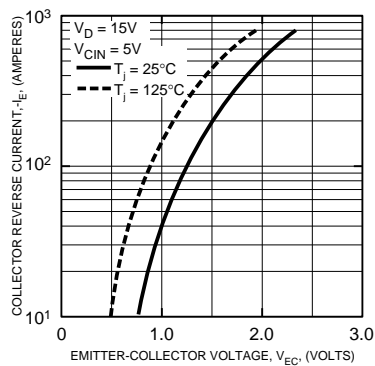
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



REVERSE RECOVERY CURRENT VS. COLLECTOR CURRENT (TYPICAL)



DIODE FORWARD CHARACTERISTICS



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FLAT-BASE TYPE
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